General Description

The MAX4475-MAX4478/MAX4488/MAX4489 wideband, low-noise, low-distortion operational amplifiers offer Rail-to-Rail[®] outputs and single-supply operation down to 2.7V. They draw 2.2mA of guiescent supply current per amplifier while featuring ultra-low distortion (0.0002% THD + N), as well as low input voltage-noise density $(4.5 \text{nV}/\sqrt{\text{Hz}})$ and low input current-noise density $(0.5fA/\sqrt{Hz})$. These features make the devices an ideal choice for applications that require low distortion and/or low noise.

For power conservation, the MAX4475/MAX4488 offer a low-power shutdown mode that reduces supply current to 0.01µA and places the amplifiers' outputs into a highimpedance state. These amplifiers have outputs which swing rail-to-rail and their input common-mode voltage range includes ground. The MAX4475-MAX4478 are unity-gain stable with a gain-bandwidth product of 10MHz. The MAX4488/MAX4489 are internally compensated for gains of +5V/V or greater with a gain-bandwidth product of 42MHz. The single MAX4475/ MAX4476/MAX4488 are available in space-saving, 6-pin SOT23 packages.

Applications

ADC Buffers **DAC Output Amplifiers** Low-Noise Microphone/Preamplifiers **Digital Scales** Strain Gauges/Sensor Amplifiers Medical Instrumentation

Typical Operating Characteristic



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

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Features

- ♦ Low Input Voltage-Noise Density: 4.5nV/√Hz
- ◆ Low Input Current-Noise Density: 0.5fA/√Hz
- Low Distortion: 0.0002% THD + N (1kΩ load)
- Single-Supply Operation from +2.7V to +5.5V
- Input Common-Mode Voltage Range Includes Ground
- Rail-to-Rail Output Swings with a 1kΩ Load
- 10MHz GBW Product, Unity-Gain Stable (MAX4475-MAX4478)
- ♦ 42MHz GBW Product, Stable with Ay ≥ +5V/V (MAX4488/MAX4489)
- Excellent DC Characteristics $V_{OS} = 70 \mu V$ $I_{BIAS} = 1pA$ Large-Signal Voltage Gain = 120dB
- Low-Power Shutdown Mode: Reduces Supply Current to 0.01µA **Places Output in High-Impedance State**
- Available in Space-Saving SOT23, µMAX, and **TSSOP** Packages

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK			
MAX4475AUT-T	-40°C to +125°C	6 SOT23-6	AAZV			
MAX4475AUA	-40°C to +125°C	8 µMAX	_			
MAX4475ASA	-40°C to +125°C	8 SO	_			
MAX4476AUT-T	-40°C to +125°C	6 SOT23-6	AAZX			
MAX4477AUA	-40°C to +125°C	8 µMAX				
Ordering Information continued at end of data sheet.						

rmation continued at end

Pin Configurations and Typical Operating Circuit appear at end of data sheet.

Selector Guide

PART	GAIN BW (MHz)	STABLE GAIN (V/V)	NO. OF AMPS	SHDN
MAX4475	10	1	1	Yes
MAX4476	10	1	1	—
MAX4477	10	1	2	—
MAX4478	10	1	4	—
MAX4488	42	5	1	Yes
MAX4489	42	5	2	_

Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

Power-Supply Voltage (V_{DD} to V_{SS}).....-0.3V to +6.0V Analog Input Voltage (IN_+, IN_-)....(V_{SS} - 0.3V) to (V_{DD} + 0.3V) SHDN Input Voltage(V_{SS} - 0.3V) to +6.0V Output Short-Circuit Duration to Either SupplyContinuous Continuous Power Dissipation (T_A = +70°C) 6-Pin SOT23 (derate 9.1mW/°C above +70°C).......727mW

	., _,
8-Pin µMAX (derate 4.5mW/°C above +70°C)	362mW
8-Pin SO (derate 5.88mW/°C above +70°C)	.471mW

14-Pin SO (derate 8.33mW/°C above +70°C)	.667mW
14-Pin TSSOP (derate 9.1mW/°C above +70°C)	.727mW
Operating Temperature Range40°C to	+125°C
Junction Temperature	.+150°C
Storage Temperature Range65°C to	+150°C
Lead Temperature (soldering, 10s)	.+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \overline{SHDN} = V_{DD}, T_A = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C.$ (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS	
Supply Voltage Range	V _{DD}	(Note 3)			2.7		5.5	V
		Normal mode		$V_{DD} = 3V$		2.2		
Quiescent Supply Current Per Amplifier	ID	Normal mode		$V_{DD} = 5V$		2.5	4.4	mA
Лаприног		Shutdown mode	(SHDN =	VSS) (Note 2)		0.01	1.0	μA
Input Offset Voltage	Vos	$T_A = +25^{\circ}C$				±70	±350	μV
input Onset Voltage	VUS	$T_A = -40^{\circ}C \text{ to } +1$	25°C				±750	μv
Input Offset Voltage Tempco	TCVOS					±0.3	±6	µV/°C
Input Bias Current	Ι _Β	(Note 4)				±1	±150	рА
Input Offset Current	IOS	(Note 4)				±1	±150	рА
Differential Input Resistance	R _{IN}		_			1000		GΩ
Input Common-Mode Voltage	VCM	Guaranteed by $T_A = +25^{\circ}C$	25°C	-0.2		V _{DD} - 1.6	V	
Range	V CIVI	CMRR Test	$T_A = -$	40°C to +125°C	-0.1		V _{DD} - 1.7	v
Common Made Dejection Datio	CMRR	(V _{SS} - 0.2V) ≤ V _{CM} ≤ (V _{DD} - 1.6V)	T _A = +	25°C	90	115		dB
Common-Mode Rejection Ratio	CIVINN	(V _{SS} - 0.1V) ≤ V _{CM} ≤ (V _{DD} - 1.7V)	T _A =	40°C to +125°C	90			uв
Power-Supply Rejection Ratio	PSRR	V _{DD} = 2.7 to 5.5\	/		90	120		dB
	Avol	$ \begin{array}{l} R_{L} = 10 \mathrm{k} \Omega \text{ to } V_{DD}/2; \\ V_{OUT} = 100 \mathrm{mV} \text{ to } (V_{DD} \text{ - } 125 \mathrm{mV}) \end{array} $		90	120			
Large-Signal Voltage Gain		$ \begin{array}{l} R_{L} = 1 \mathrm{k} \Omega \text{ to } V_{DD}/2 \mathrm{;} \\ V_{OUT} = 200 \mathrm{mV} \text{ to } (V_{DD} - 250 \mathrm{mV}) \end{array} $		85	110		dB	
		$R_L = 500\Omega$ to V_{DI} $V_{OUT} = 350$ mV to		500mV)	85	110		

DC ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \overline{SHDN} = V_{DD}, T_A = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C.$ (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS
		IV _{IN+} - V _{IN-} I ≥ 10mV,	V _{DD} - V _{OH}		10	45	
		$R_L = 10 k\Omega$ to $V_{DD}/2$	V _{OL} - V _{SS}		10	40	
Output Voltago Swing	Vout	$ V_{IN+} - V_{IN-} \ge 10 \text{mV},$	V _{DD} - V _{OH}		80	200	mV
Output Voltage Swing	V001	$R_L = 1k\Omega$ to $V_{DD}/2$	V _{OL} - V _{SS}		50	150	IIIV
	IVIN	IV _{IN+} - V _{IN-} I ≥ 10mV,	V _{DD} - V _{OH}		100	300	
		$R_L = 500\Omega$ to $V_{DD}/2$	V _{OL} - V _{SS}		80	250	
Output Short-Circuit Current	Isc				48		mA
Output Leakage Current	ILEAK	Shutdown mode (\overline{SHDN} V _{OUT} = V _{SS} to V _{DD}	Shutdown mode ($\overline{SHDN} = V_{SS}$), V _{OUT} = V _{SS} to V _{DD}		±0.001	±1.0	μA
SHDN Logic Low	VIL					$0.3 \times V_{DD}$	V
SHDN Logic High	VIH			$0.7 \times V_{DD}$			V
SHDN Input Current		$\overline{SHDN} = V_{SS}$ to V_{DD}			0.01	1	μA
Input Capacitance	CIN				10		рF

AC ELECTRICAL CHARACTERISTICS

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \overline{SHDN} = V_{DD}, T_A = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONDITI	ONS	MIN	TYP	МАХ	UNITS	
Onin Daviduidhe Draduat		MAX4475-MAX4478	$A_V = +1V/V$	10				
Gain-Bandwidth Product	GBWP	MAX4488/MAX4489	$A_V = +5V/V$		42		MHz	
Slew Rate	SR	MAX4475-MAX4478	$A_V = +1V/V$		3		Mue	
Siew Rate	эп	MAX4488/MAX4489	$A_V = +5V/V$		10		V/µs	
Full Devicer Deviction (Nate 5)		MAX4475-MAX4478	$A_V = +1V/V$		0.4			
Full-Power Bandwidth (Note 5)		MAX4488/MAX4489	$A_V = +5V/V$		1.25		MHz	
Peak-to-Peak Input Noise Voltage	e _{n(P-P)}	f = 0.1Hz to 10Hz			260		nV _{P-P}	
		f = 10Hz			21			
Input Voltage-Noise Density	en	f = 1kHz		4.5		nV/√Hz		
		f = 30kHz		3.5				
Input Current-Noise Density	in	f = 1kHz			0.5		fA/√Hz	
		$V_{OUT} = 2V_{P-P},$ $A_V = +1V/V$	f = 1kHz		0.0002			
		$(MAX4475-MAX4478), \\ R_L = 10 k\Omega \text{ to GND}$	f = 20kHz		0.0007			
Total Harmonic Distortion Plus		$V_{OUT} = 2V_{P-P},$ $A_V = +1V/V$	f = 1kHz		0.0002			
Noise (Note 6)	THD + N	(MAX4475–MAX4478), R _L = 1k Ω to GND	f = 20kHz		0.001		%	
		V _{OUT} = 2V _{P-P} , A _V = +5V/V	f = 1kHz		0.0004			
		(MAX4488/MAX4489), R _L = 10k Ω to GND	f = 20kHz		0.0006			

AC ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \overline{SHDN} = V_{DD}, T_A = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS
Total Harmonic Distortion Plus	THD + N	$V_{OUT} = 2V_{P-P},$ $A_V = +5V/V$	f = 1kHz		0.0005		%
Noise (Note 6)		(MAX4488/MAX4489), R _L = 1k Ω to GND	f = 20kHz		0.008		70
Capacitive-Load Stability		No sustained oscillations			200		pF
Gain Margin	GM				12		dB
Phase Margin	ΦM	MAX4475–MAX4478, Av = +1V/V			70		dograda
Phase Margin	ΨΙνΙ	MAX4488/MAX4489, A _V = +5V/V			80		degrees
Settling Time		To 0.01%, V _{OUT} = 2V st	To 0.01%, V _{OUT} = 2V step		2		μs
Delay Time to Shutdown	tsh				1.5		μs
Enable Delay Time from Shutdown	t _{EN}	V_{OUT} = 2.5V, V_{OUT} settles to 0.1%			10		μs
Power-Up Delay Time		V_{DD} = 0 to 5V step, V_{OUT} stable to 0.1%			13		μs

Note 1: All devices are 100% tested at $T_A = +25^{\circ}C$. Limits over temperature are guaranteed by design.

Note 2: SHDN is available on the MAX4475/MAX4488 only.

Note 3: Guaranteed by the PSRR test.

Note 4: Guaranteed by design.

Note 5: Full-power bandwidth for unity-gain stable devices (MAX4475–MAX4478) is measured in a closed-loop gain of +2V/V to accommodate the input voltage range, V_{OUT} = 4V_{P-P}.

Note 6: Lowpass-filter bandwidth is 22kHz for f = 1kHz and 80kHz for f = 20kHz. Noise floor of test equipment = $10nV/\sqrt{Hz}$.

Typical Operating Characteristics

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L$ tied to $V_{DD}/2$, input noise floor of test equipment =10nV/ \sqrt{Hz} for all distortion measurements, $T_A = +25^{\circ}C$, unless otherwise noted.)



Typical Operating Characteristics (continued)



MAX4475-MAX4478/MAX4488/MAX4489

5

measurements, $T_A = +25^{\circ}C$, unless otherwise noted.) **INPUT OFFSET VOLTAGE SUPPLY CURRENT vs. SUPPLY VOLTAGE SUPPLY CURRENT vs. OUTPUT VOLTAGE** vs. SUPPLY VOLTAGE 3.0 3.0 20 PER AMPLIFIER $V_{DD} = 5V$ 15 2.5 2.5 NPUT OFFSET VOLTAGE (µV) 10 SUPPLY CURRENT (mA) 2.0 2.0 $V_{DD} = 3V$ 5 1.5 1.5 0 -5 1.0 1.0 -10 0.5 0.5 -15 0 0 -20 2.5 3.0 3.5 4.0 4.5 5.0 5.5 0 1 2 3 4 5 2.5 3.0 4.0 5.5 3.5 4.5 5.0 SUPPLY VOLTAGE (V) OUTPUT VOLTAGE (V) SUPPLY VOLTAGE (V) MAX4475-MAX4478 MAX4488/MAX4489 GAIN AND PHASE vs. FREQUENCY GAIN AND PHASE vs. FREQUENCY 60 180 60 180 = 3V OR 5V /_{DD} 50 144 50 144 $R_L = 50k\Omega$ C_{L} = 20pF 40 108 108 40 $A_V = +1000V/V$ 30 72 30 72 20 36 PHASE (degrees 20 36 (degrees) GAIN (dB) GAIN (dB) 10 0 10 0 PHASE (-36 0 -36 0 -72 -10 -72 -10 $V_{DD} = 3V \text{ OR } 5V$ -20 -108 -20 -108 $R_L = 50k\Omega$ = 20pF Cı -30 -144 -30 -144 +1000V/V Av -40 -180 -180 -40 100M 100 10k 100k 1M 10M 100 100M 1k 1k 10k 100k 1M 10M INPUT FREQUENCY (Hz) INPUT FREQUENCY (Hz) MAX4475-MAX4478 **POWER-SUPPLY REJECTION RATIO** vs. FREQUENCY **OUTPUT IMPEDANCE vs. FREQUENCY** 1000 0 = 3V OB 5VV_DD -10 -20 100 -30 OUTPUT IMPEDANCE (Ω) -40 -50 10 (dd) hhch -60 $A_V = +5$ -70 1 -80 -90 Av -100 0.1 -110 -120 0.01 -130 100 10k 1 10 1k 0.001 0.1 10 1000 100,000 FREQUENCY (Hz) FREQUENCY (kHz)

/N/IXI/N

Typical Operating Characteristics (continued) $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L$ tied to $V_{DD}/2$, input noise floor of test equipment = $10N/\sqrt{Hz}$ for all distortion

SUPPLY CURRENT (mA)



/N/XI/N

7

_Typical Operating Characteristics (continued)

 $(V_{DD} = +5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, \text{ input noise floor of test equipment } = 10 \text{nV}/\sqrt{\text{Hz}} \text{ for all distortion} \text{ measurements}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.}$

MAX4488/MAX4489 LARGE-SIGNAL PULSE RESPONSE MAX4475 to







Pin Description

		PIN				
MAX4475/ MAX4488	MAX4475/ MAX4488	MAX4476	MAX4477/ MAX4489	MAX4478	NAME	FUNCTION
SOT23	SO/µMAX	SOT23	SO/µMAX	SO/TSSOP		
1	6	1	1, 7	1, 7, 8, 14	OUT, OUTA, OUTB, OUTC, OUTD	Amplifier Output
2	4	2	4	11	V _{SS}	Negative Supply. Connect to ground for single- supply operation
3	3	3	3, 5	3, 5, 10, 12	IN+, INA+, INB+, INC+, IND+	Noninverting Amplifier Input
4	2	4	2, 6	2, 6, 9, 13	IN-, INA-, INB-, INC-, IND-	Inverting Amplifier Input
6	7	6	8	4	V _{DD}	Positive Supply
5	8	_	_	_	SHDN	Shutdown Input. Connect to V _{DD} for normal operation (amplifier(s) enabled).
_	1, 5	5	—	_	N.C.	No Connection. Not internally connected.



Detailed Description

The MAX4475–MAX4478/MAX4488/MAX4489 singlesupply operational amplifiers feature ultra-low noise and distortion. Their low distortion and low noise make them ideal for use as preamplifiers in wide dynamicrange applications, such as 16-bit analog-to-digital converters (see *Typical Operating Circuit*). Their highinput impedance and low noise are also useful for signal conditioning of high-impedance sources, such as piezoelectric transducers.

These devices have true rail-to-rail ouput operation, drive loads as low as $1k\Omega$ while maintining DC accuracy, and can drive capactive loads up to 200pF without oscillation. The input common-mode voltage range extends from (V_{DD} - 1.6V) to 200mV below the negative rail. The push-pull output stage maintains excellent DC characteristics, while delivering up to ±5mA of current.

The MAX4475–MAX4478 are unity-gain stable, while the MAX4488/MAX4489 have a higher slew rate and are stable for gains \geq 5V/V. The MAX4475/MAX4488 feature a low-power shutdown mode, which reduces the supply current to 0.01µA and disables the outputs.

Low Distortion

Many factors can affect the noise and distortion that the device contributes to the input signal. The following guidelines offer valuable information on the impact of design choices on Total Harmonic Distortion (THD).

Choosing proper feedback and gain resistor values for a particular application can be a very important factor in reducing THD. In general, the smaller the closedloop gain, the smaller the THD generated, especially when driving heavy resistive loads. The THD of the part normally increases at approximately 20dB per decade, as a function of frequency. Operating the device near or above the full-power bandwidth significantly degrades distortion.

Referencing the load to either supply also improves the part's distortion performance, because only one of the MOSFETs of the push-pull output stage drives the output. Referencing the load to midsupply increases the part's distortion for a given load and feedback setting. (See the Total Harmonic Distortion vs. Frequency graph in the *Typical Operating Characteristics*.)

For gains ≥ 5 V/V, the decompensated devices MAX4488/MAX4489 deliver the best distortion performance, since they have a higher slew rate and provide a higher amount of loop gain for a given closed-loop gain setting. Capacitive loads below 100pF do not significantly affect distortion results. Distortion performance is relatively constant over supply voltages.



Figure 1. Adding Feed-Forward Compensation







Figure 2b. Pulse Response with 10pF Feed-Forward Compensation



Low Noise

The amplifier's input-referred noise-voltage density is dominated by flicker noise at lower frequencies, and by thermal noise at higher frequencies. Because the thermal noise contribution is affected by the parallel combination of the feedback resistive network (R_F II R_G, Figure 1), these resistors should be reduced in cases where the system bandwidth is large and thermal noise is dominant. This noise contribution factor decreases, however, with increasing gain settings.

For example, the input noise-voltage density of the circuit with R_F = 100k Ω , R_G = 11k Ω (Av = +5V/V) is $e_{\rm n}$ = 14nV/ $\sqrt{\rm Hz}$, $e_{\rm n}$ can be reduced to 6nV/ $\sqrt{\rm Hz}$ by choosing R_F = 10k Ω , R_G = 1.1k Ω (Av = +5V/V), at the expense of greater current consumption and potentially higher distortion. For a gain of 100V/V with R_F = 100k Ω , R_G = 1.1k Ω , the $e_{\rm n}$ is still a low 6nV/ $\sqrt{\rm Hz}$.

Using a Feed-Forward Compensation Capacitor, Cz

The amplifier's input capacitance is 10pF. If the resistance seen by the inverting input is large (feedback network), this can introduce a pole within the amplifier's bandwidth resulting in reduced phase margin. Compensate the reduced phase margin by introducing a feed-forward capacitor (C_Z) between the inverting input and the output (Figure 1). This effectively cancels the pole from the inverting input of the amplifier. Choose the value of C_Z as follows:

 $C_Z = 10 \times (R_F / R_G) [pF]$

In the unity-gain stable MAX4475–MAX4478, the use of a proper C_Z is most important for A_V = +2V/V, and A_V = -1V/V. In the decompensated MAX4488/MAX4489, C_Z is most important for A_V = +10V/V. Figures 2a and 2b show transient response both with and without C_Z.

Using a slightly smaller Cz than suggested by the formula above achieves a higher bandwidth at the expense of reduced phase and gain margin. As a general guideline, consider using Cz for cases where R_G II R_F is greater than 20k Ω (MAX4475–MAX4478) or greater than 5k Ω (MAX4488/MAX4489).

Applications Information

The MAX4475–MAX4478/MAX4488/MAX4489 combine good driving capability with ground-sensing input and rail-to-rail output operation. With their low distortion and low noise, they are ideal for use in ADC buffers, medical instrumentation systems and other noise-sensitive applications.



Figure 3. Overdriven Input Showing No Phase Reversal



Figure 4. Rail-to-Rail Output Operation

Ground-Sensing and Rail-to-Rail Outputs

The common-mode input range of these devices extends below ground, and offers excellent commonmode rejection. These devices are guaranteed not to undergo phase reversal when the input is overdriven (Figure 3).

Figure 4 showcases the true rail-to-rail output operation of the amplifier, configured with $A_V = 5V/V$. The output swings to within 8mV of the supplies with a 10k Ω load, making the devices ideal in low-supply voltage applications.

Power Supplies and Layout

The MAX4475–MAX4478/MAX4488/MAX4489 operate from a single +2.7V to +5.5V power supply or from dual supplies of $\pm 1.35V$ to $\pm 2.75V$. For single-supply operation, bypass the power supply with a 0.1µF ceramic



Typical Application Circuit







capacitor placed close to the $V_{\mbox{DD}}$ pin. If operating from dual supplies, bypass each supply to ground.

Good layout improves performance by decreasing the amount of stray capacitance and noise at the op amp's inputs and output. To decrease stray capacitance, minimize PC board trace lengths and resistor leads, and place external components close to the op amp's pins.

Typical Application Circuit

The *Typical Application Circuit* shows the single MAX4475 configured as an output buffer for the MAX5541 16-bit DAC. Because the MAX5541 has an unbuffered voltage output, the input bias current of the op amp used must be less than 6nA to maintain 16-bit accuracy. The MAX4475 has an input bias current of only 150pA (max), virtually eliminating this as a source

of error. In addition, the MAX4475 has excellent openloop gain and common-mode rejection, making this an excellent ouput buffer amplifier.

DC-Accurate Lowpass Filter

The MAX4475–MAX4478/MAX4488/MAX4489 offer a unique combination of low noise, wide bandwidth, and high gain, making them an excellent choice for active filters up to 1MHz. The *Typical Operating Circuit* shows the dual MAX4477 configured as a 5th order Chebyschev filter with a cutoff frequency of 100kHz. The circuit is implemented in the Sallen-Key topology, making this a DC-accurate filter.

MAX4475-MAX4478/MAX4488/MAX4489



Pin Configurations TOP VIEW TOP VIEW 8 SHDN N.C. OUTA 8 V_{DD} AXIM 7 V_{DD} NXXM 7 OUTB INA- 2 INA- 2 MAX4475 MAX4477 INA+ 3 MAX4488 6 OUT INA+ 3 MAX4489 6 INB-V_{SS} 4 V_{SS} 4 5 N.C. 5 INB+ SO/uMAX SO/µMAX TOP VIEW TOP VIEW TOP VIEW OUTA 14 OUTD 1 OUT 6 V_{DD} 1 6 V_{DD} OUT INA-2 13 IND-ΝΙΧΙΜ MIXIM MAX4475 MAX4476 12 IND+ INA+ 3 5 N.C. V_{SS} 2 5 SHDN MIXI/M V_{SS} 2 MAX4488 V_{DD} 4 MAX4478 11 V_{SS} INB+ 5 10 INC+ IN+ 3 4 IN-IN+ 3 4 IN-9 INC-INB-6 8 OUTC SOT23-6 SOT23-6 OUTB 7 SO/TSSOP

Ordering Information (continued)

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4477AUA	-40°C to +125°C	8 µMAX	
MAX4477ASA	-40°C to +125°C	8 SO	_
MAX4478AUD	-40°C to +125°C	14 TSSOP	_
MAX4478ASD	-40°C to +125°C	14 SO	_
MAX4488AUT-T	-40°C to +125°C	6 SOT23-6	AAZW
MAX4488AUA	-40°C to +125°C	8 µMAX	_
MAX4488ASA	-40°C to +125°C	8 SO	
MAX4489AUA	-40°C to +125°C	8 µMAX	_
MAX4489ASA	-40°C to +125°C	8 SO	_

Chip Information

MAX4475/MAX4476 TRANSISTOR COUNT: 1095 MAX4477 TRANSISTOR COUNT: 2132 MAX4478 TRANSISTOR COUNT: 4244 MAX4488 TRANSISTOR COUNT: 1095 MAX4489 TRANSISTOR COUNT: 2132 PROCESS: BICMOS

MAX4475-MAX4478/MAX4488/MAX4489

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



Package Information (continued)

MIXIM

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)





Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



MAX4475-MAX4478/MAX4488/MAX4489

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15